



Seat No. : _____

TC-118

April-2013

M.Sc. Sem. II

410 : Physics

(Remote Sensing and Electronics)

Time : 3 Hours]

[Max. Marks : 70

- Instructions :** (1) All symbols carry usual meanings.
(2) Attempt all questions.
(3) Scientific calculators are allowed.

1. (a) Describe in detail how Earth's atmosphere affects remote sensing from space. 7

OR

What is meant by spectral signature ? Describe the spectral signatures of vegetation and water bodies in the visible-IR (0.3 to 3 μm) spectral range. What are the physical basis for this signatures ? How healthy and unhealthy vegetation can be discriminated using spectral signature.

- (b) Discuss the different platforms employed in Remote Sensing stating their advantages and disadvantages. Describe the whiskbroom and pushbroom scanning techniques used for remote sensing. 7

OR

Describe range and azimuth resolution of a Side Looking Airborne Radar (SLAR). Explain in detail how the range and azimuth resolutions vary over the swath of a SALR.

2. (a) What are the advantages of digital image processing compared to visual image processing. Describe various elements of visual image interpretation. What is meant by interpretation keys ? 7

OR

What is meant by digital image and histogram of an image. Describe with equations wherever applicable the different image enhancement techniques.

- (b) What is meant by spatial frequency ? Based on spatial frequency distinguish between rough and smooth textures in image. Discuss the concept of convolution and spatial filtering ? With help of examples discuss various methods of spatial filtering. 7

OR

Describe supervised and unsupervised classification used in remote sensing, mention their merits and demerits.

3. (a) Using N-channel JFET, draw circuit of common source amplifier and obtain the expressions of voltage gain, input and output resistances at mid frequencies. 7

OR

Give the constructional details of JFET and explain its working principle.

- (b) Give the details of construction of depletion type N-channel MOSFET. Draw its drain characteristics and transfer characteristics. 7

OR

Explain the effect of drain to source voltage (V_{ds}) on channel conductivity of N-channel JFET with suitable diagrams.

4. (a) Draw schematic circuit diagram of 2-input NMOS-NAND gate and explain its working by verifying the truth table. 7

OR

Discuss the following terms for digital ICs :

- (i) Propagation delay
 - (ii) Noise Immunity
 - (iii) Power Dissipation
- (b) Describe the three different methods to interface TTL driver ICs to CMOS load ICs. 7

OR

What is meant by sourcing and sinking currents ? Discuss standard loading rules for TTL ICs.

5. Answer the following : (**One mark each**) 14

- (a) Draw the Planck's spectral distribution curve for sun and that of earth surface.
- (b) Suppose you have a digital image which has a radiometric resolution of 10 bits. What is the maximum value of the digital number which could be represented in that image ?
- (c) A surface is having average height variation of 5 mm. Using Rayleigh Criteria, verify whether the surface is rough or smooth for vertically falling (i) visible radiation (ii) microwave radiation.
- (d) What is the major limitation of SLAR ?
- (e) Obtain Rayleigh-jeans approximation from the Planck's equation.
- (f) What is meant by sun synchronous orbit ?
- (g) List the three image data re-sampling techniques.
- (h) List the two advantages of digital ICs.
- (i) Draw the symbol of Dual gate P-MOSFET.
- (j) Draw static characteristics of JFET and show "PINCH OFF Region" ?
- (k) The ICs of CMOS family have lowest power dissipation. True or False.
- (l) Three CMOS devices are cascaded. If each has got the propagation delay time of 100 ns, what is the total propagation delay time ?
- (m) Write two advantages of ECL ICs.
- (n) FET is a Voltage controlled device. True or False.